

■ Absolute Maximum Ratings $T_a = 25^\circ\text{C}$

Parameter		Symbol	Rating	Unit
Input (Light emitting diode)	Reverse voltage	CNZ1021	3	V
		CNZ1023	3	
		CNA1009H	5	
	Forward current	I_F	50	mA
	Power dissipation *1	P_D	75	mW
Output (Photo transistor)	Collector-emitter voltage (Base open)	V_{CEO}	30	V
	Emitter-collector voltage (Base open)	V_{ECO}	5	V
	Collector current	I_C	20	mA
	Collector power dissipation *2	P_C	100	mW
Temperature	Operating ambient temperature	T_{opr}	-25 to +85	$^\circ\text{C}$
	Storage temperature	T_{stg}	-40 to +100	$^\circ\text{C}$

Note) *1: Input power derating ratio is 1.0 mW/ $^\circ\text{C}$ at $T_a \geq 25^\circ\text{C}$.

*2: Output power derating ratio is 1.33 mW/ $^\circ\text{C}$ at $T_a \geq 25^\circ\text{C}$.

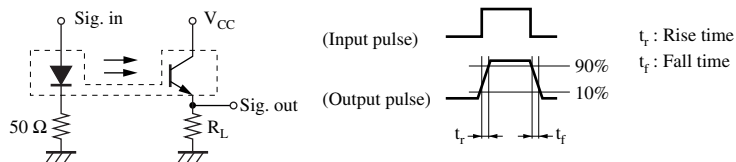
■ Electrical-Optical Characteristics $T_a = 25^\circ\text{C} \pm 3^\circ\text{C}$

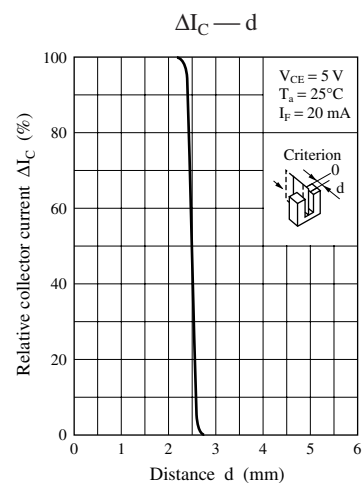
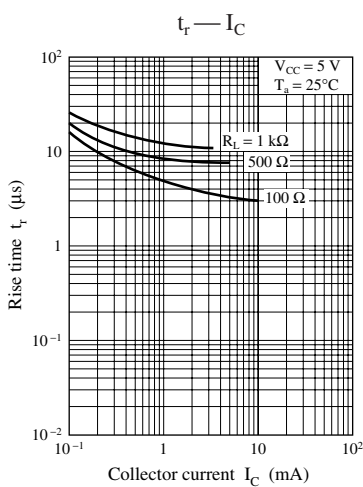
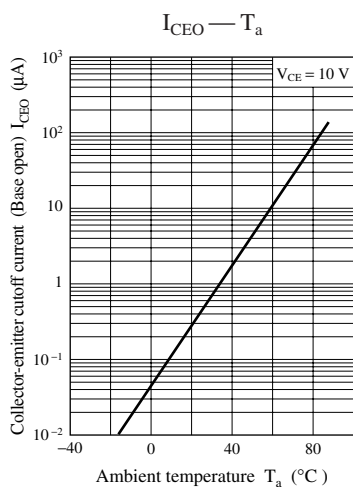
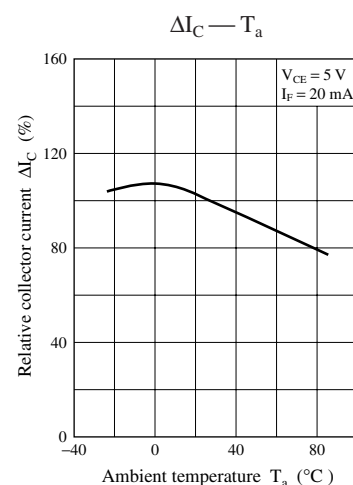
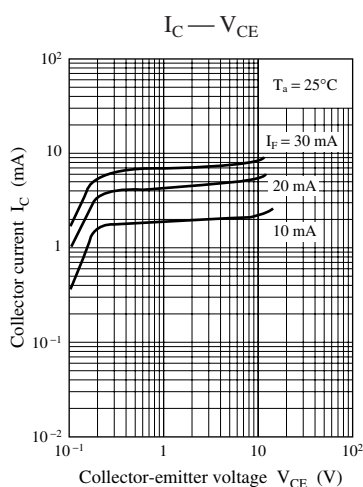
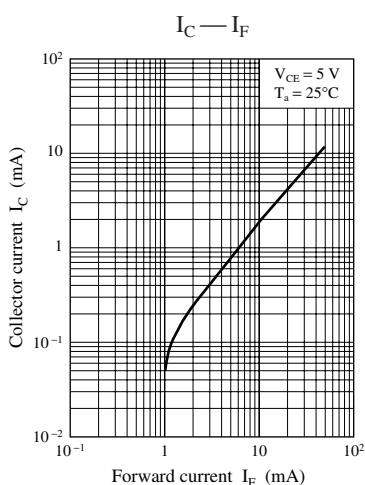
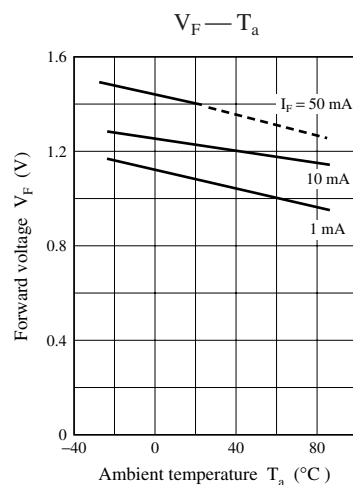
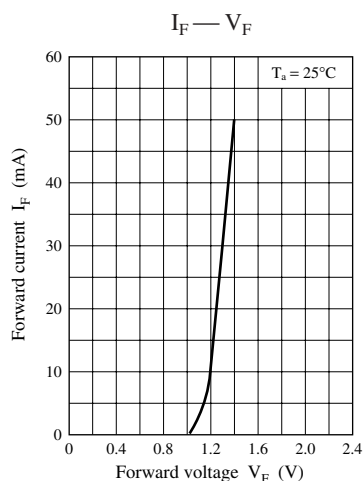
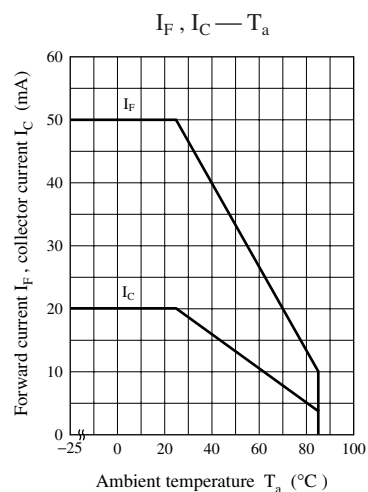
Parameter		Symbol	Conditions	Min	Typ	Max	Unit
Input characteristics	Forward voltage	V_F	$I_F = 20 \text{ mA}$		1.25	1.40	V
	Reverse current	I_R	$V_R = 3 \text{ V}$			10	μA
Output characteristics	Collector-emitter cutoff current (Base open)	I_{CEO}	$V_{CE} = 10 \text{ V}$		10	200	nA
Transfer characteristics	Collector current	I_C	$V_{CC} = 5 \text{ V}, I_F = 20 \text{ mA}, R_L = 100 \Omega$	0.5		15.0	mA
	Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_F = 40 \text{ mA}, I_C = 1 \text{ mA}$			0.4	V
	Rise time *	t_r	$V_{CC} = 5 \text{ V}, I_C = 1 \text{ mA}$		5		μs
	Fall time *	t_f	$R_L = 100 \Omega$		5		μs

Note) 1. Input and output are practiced by electricity.

2. This device is designed be disregarded radiation.

3. *: Switching time measurement circuit





Caution for Safety

 **DANGER**

■ This product contains Gallium Arsenide (GaAs).

GaAs powder and vapor are hazardous to human health if inhaled or ingested. Do not burn, destroy, cut, cleave off, or chemically dissolve the product. Follow related laws and ordinances for disposal. The product should be excluded from general industrial waste or household garbage.

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